

<p><b>SURFACE MOUNT SCHOTTKY BARRIER RECTIFIERS</b></p> <p><b>FEATURES</b></p> <ul style="list-style-type: none"> <li>● Metal-Semiconductor junction with gard ring</li> <li>● Epitaxial construction</li> <li>● Low forward voltage drop</li> <li>● High current capability</li> <li>● The plastic material carries UL recognition 94V-0</li> <li>● For use in low vlotage, high frequency inverters, free wheeling, and polarity protection applications</li> </ul> <p><b>MECHANICAL DATA</b></p> <ul style="list-style-type: none"> <li>●Case: Molded Plastic</li> <li>●Polarity:Color band denotes cathode</li> <li>●Weight: 0.007 ounces,0.21 grams</li> </ul>	<p>REVERSE VOLTAGE - <b>20</b> to <b>100</b> Volts FORWARD CURRENT - <b>5.0</b> Amperes</p> <p style="text-align: center;"><b>SMC</b></p> <p style="text-align: center;">Dimensions in inches and (millimeters)</p>
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**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Rating at 25°C ambient temperature unless otherwise specified.  
 Single phase, half wave ,60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	SS52	SS53	SS54	SS55	SS56	SS58	SS510	UNIT	
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	V	
Maximum RMS Voltage	V <sub>RMS</sub>	14	21	28	35	42	56	70	V	
Maximum DC Blocking Voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	V	
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Lengths @T <sub>L</sub> =95 °C	I <sub>(AV)</sub>	5.0							A	
Peak Forward Surage Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load(JEDEC Method)	I <sub>FSM</sub>	150							A	
Maximum Forward Voltage at 5.0A DC	V <sub>F</sub>	0.45	0.55	0.6	0.7		0.85		V	
Maximum DC Reverse Current @T <sub>J</sub> =25°C at Rated DC Bolcking Voltage @T <sub>J</sub> =100°C	I <sub>R</sub>	1.0				50				mA
Typical Junction Capacitance (Note1)	C <sub>J</sub>	500			350				pF	
Typical Thermal Resistance (Note2)	R <sub>θJA</sub>	15			10				°C/W	
Operating Temperature Range	T <sub>J</sub>	-55 to +150							°C	
Storage Temperature Range	T <sub>STG</sub>	-55 to +150							°C	

NOTES: 1.Measured at 1.0 MHz and applied reverse voltage of 4.0V DC  
 2.Thermal resistance junction to ambient,

FIG. 1 – FORWARD CURRENT DERATING CURVE

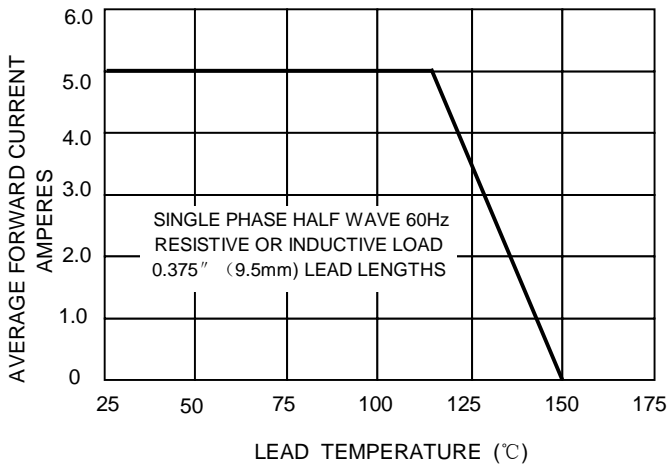


FIG. 2 – MAXIMUM NON-REPETITIVE SURGE CURRENT

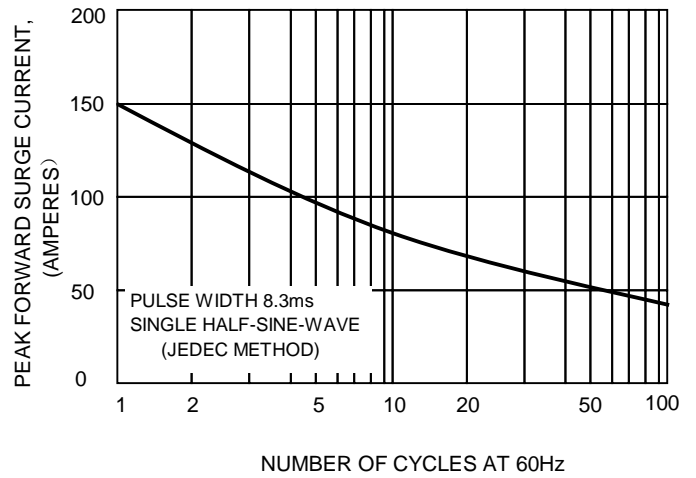


FIG.3 – TYPICAL JUNCTION CAPACITANCE

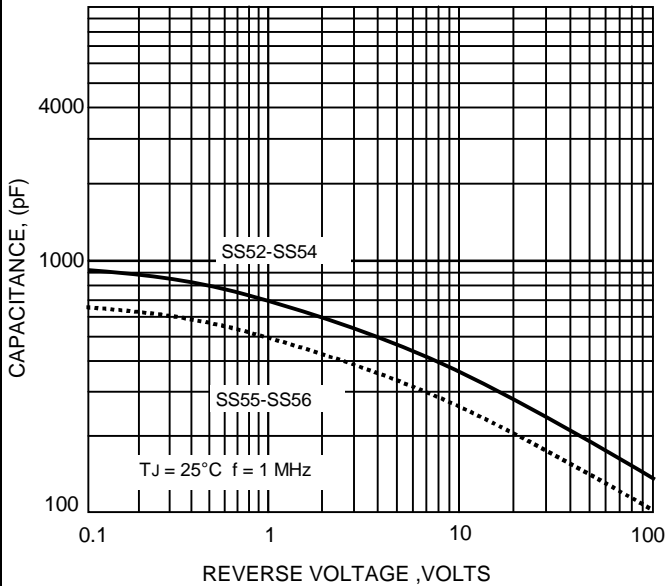


FIG.4-TYPICAL FORWARD CHARACTERISTICS

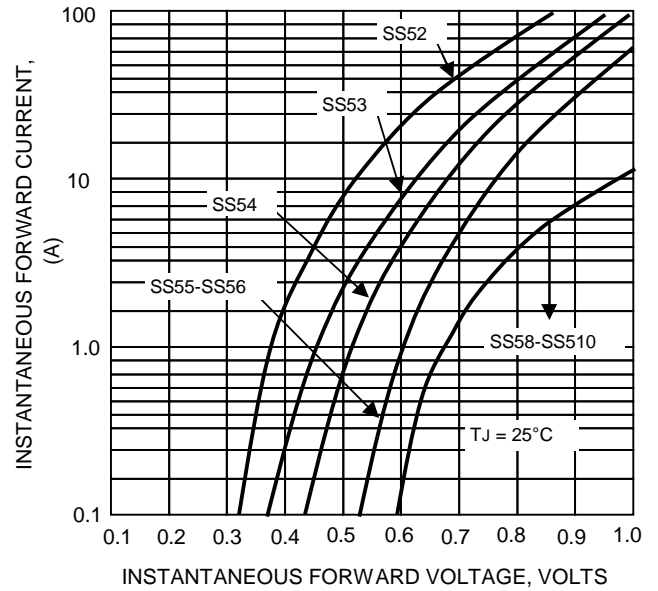


FIG.2-TYPICAL REVER CHARACTERISTICS

